

**Features**

Low gate charge  
 100% avalanche tested  
 Improved dv/dt capability  
 RoHS compliant  
 Halogen free package  
 JEDEC Qualification

$$V_{DSS} = 990 \text{ V @ } T_{jmax}$$

$$I_D = 7 \text{ A}$$

$$R_{DS(ON)} = 1.9 \text{ (max) @ } V_{GS} = 10 \text{ V}$$

**Absolute Maximum Ratings**

Parameter	Symbol	TMP7N90	TMPF7N90G	Unit	
Drain-Source Voltage	$V_{DSS}$	900		V	
Gate-Source Voltage	$V_{GS}$	30		V	
Continuous Drain Current	$I_D$	$T_C = 25$	7	7 *	A
		$T_C = 100$	4.31	4.31 *	A
Pulsed Drain Current (Note 1)	$I_{DM}$	28	28*	A	
Single Pulse Avalanche Energy (Note 2)	$E_{AS}$	106		mJ	
Repetitive Avalanche Current (Note 1)	$I_{AR}$	7		A	
Repetitive Avalanche Energy (Note 1)	$E_{AR}$	25		mJ	
Power Dissipation	$P_D$	$T_C = 25$	250	40.3	W
		Derate above 25	2	0.32	W/
Peak Diode Recovery dv/dt (Note 3)	dv/dt	4.5		V/ns	
Operating Junction and Storage Temperature Range	$T_J, T_{STG}$	-55~150			
Maximum lead temperature for soldering purposes,	$T_L$	300			

**Thermal Characteristics**

Parameter	Symbol	TMP7N90	TMPF7N90G	Unit
Maximum Thermal resistance, Junction-to-Case	$R_{JC}$	0.5	3.1	/W
Maximum Thermal resistance, Junction-to-Ambient	$R_{JA}$	62.5		

**Electrical Characteristics :  $T_C=25$  , unless otherwise noted**

Parameter	Symbol	Test condition	Min	Typ	Max	Units
<b>OFF</b>						
Drain-Source Breakdown Voltage	$BV_{DSS}$	$V_{GS} = 0\text{ V}, I_D = 250\ \mu\text{A}$	900	--	--	V
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = 900\text{ V}, V_{GS} = 0\text{ V}$	--	--	10	$\mu\text{A}$
		$V_{DS} = 720\text{ V}, T_C = 125\text{ C}$	--	--	100	$\mu\text{A}$
Forward Gate-Source Leakage Current	$I_{GSSF}$	$V_{GS} = 30\text{ V}, V_{DS} = 0\text{ V}$	--	--	100	nA
Reverse Gate-Source Leakage Current	$I_{GSSR}$	$V_{GS} = -30\text{ V}, V_{DS} = 0\text{ V}$	--	--	-100	nA

**ON**

Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250\ \mu\text{A}$	2	--	4	V
Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS} = 10\text{ V}, I_D = 3.5\text{ A}$	--	1.52	1.9	
Forward Transconductance <sup>(Note 4)</sup>	$g_{FS}$	$V_{DS} = 30\text{ V}, I_D = 3.5\text{ A}$	--	7	--	S

**DYNAMIC**

Input Capacitance	$C_{iss}$	$V_{DS} = 25\text{ V}, V_{GS} = 0\text{ V},$ $f = 1.0\text{ MHz}$	--	1969	--	pF
Output Capacitance	$C_{oss}$		--	133	--	pF
Reverse Transfer Capacitance	$C_{rss}$		--	11	--	pF

**SWITCHING**

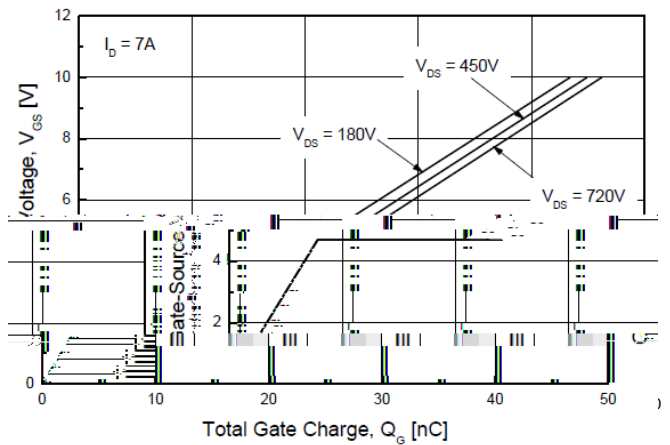
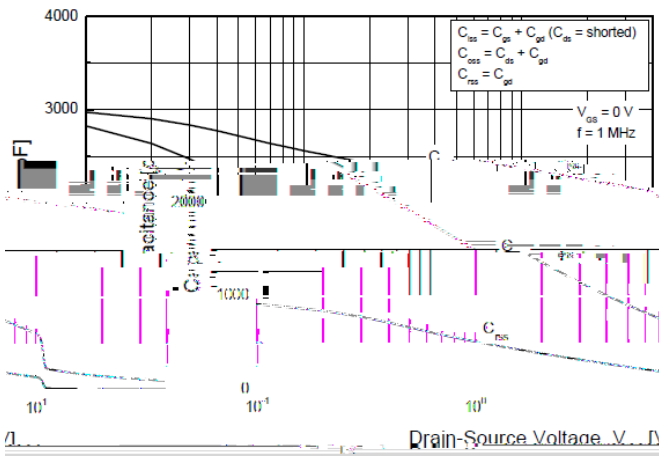
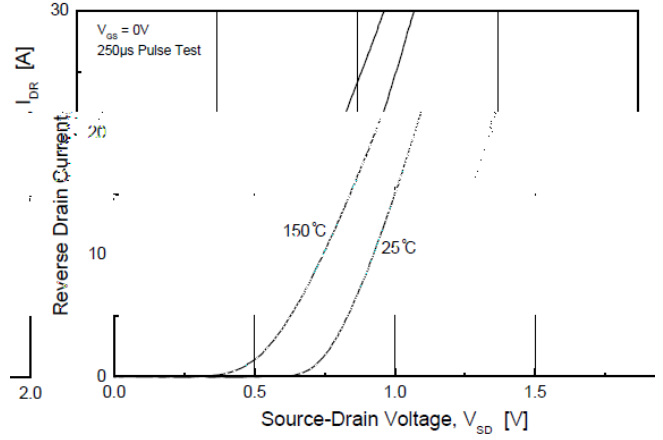
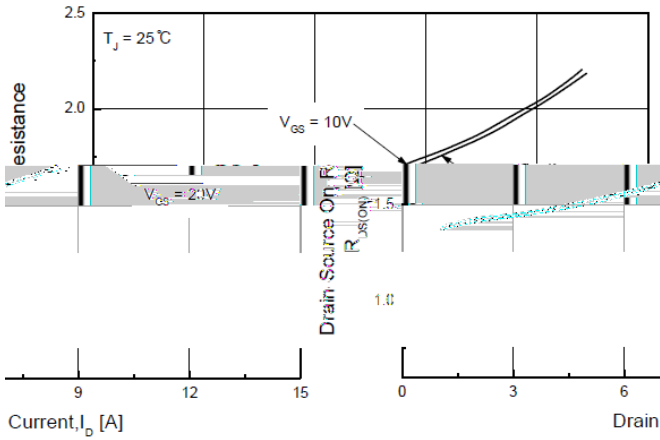
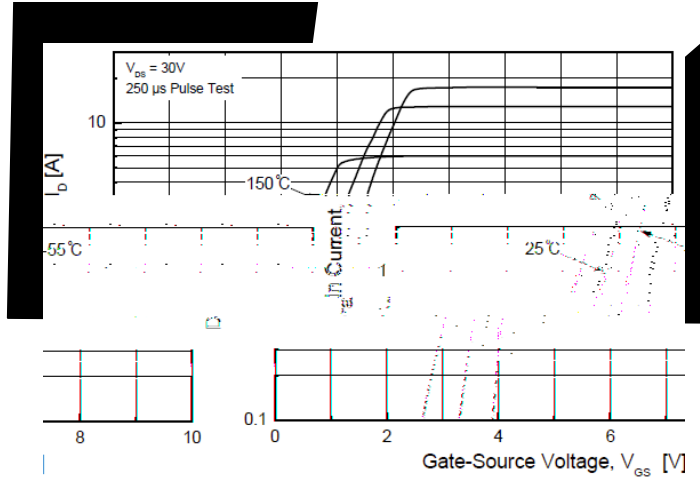
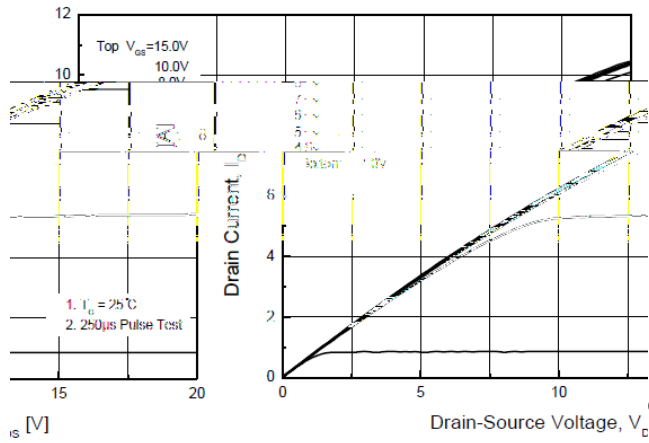
Turn-On Delay Time <sup>(Note 4,5)</sup>	$t_{d(on)}$	$V_{DD} = 450\text{ V}, I_D = 7\text{ A},$ $R_G = 25$	--	39	--	ns
Turn-On Rise Time <sup>(Note 4,5)</sup>	$t_r$		--	38	--	ns
Turn-Off Delay Time <sup>(Note 4,5)</sup>	$t_{d(off)}$		--	155	--	ns
Turn-Off Fall Time <sup>(Note 4,5)</sup>	$t_f$		--	45	--	ns
Total Gate Charge <sup>(Note 4,5)</sup>	$Q_g$	$V_{DS} = 720\text{ V}, I_D = 7\text{ A},$ $V_{GS} = 10\text{ V}$	--	49	--	nC
Gate-Source Charge <sup>(Note 4,5)</sup>	$Q_{gs}$		--	7	--	nC
Gate-Drain Charge <sup>(Note 4,5)</sup>	$Q_{gd}$		--	20	--	nC

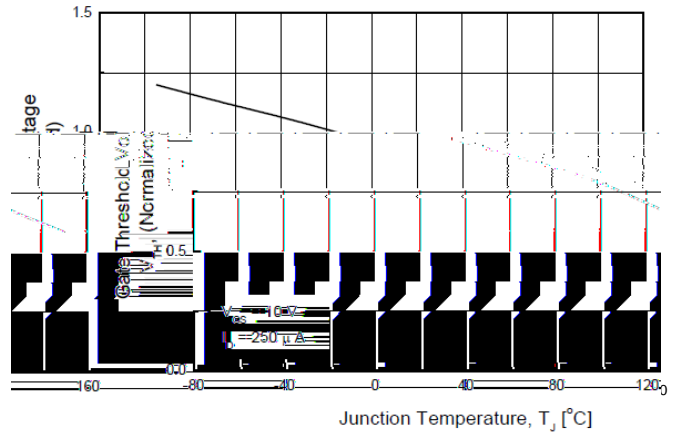
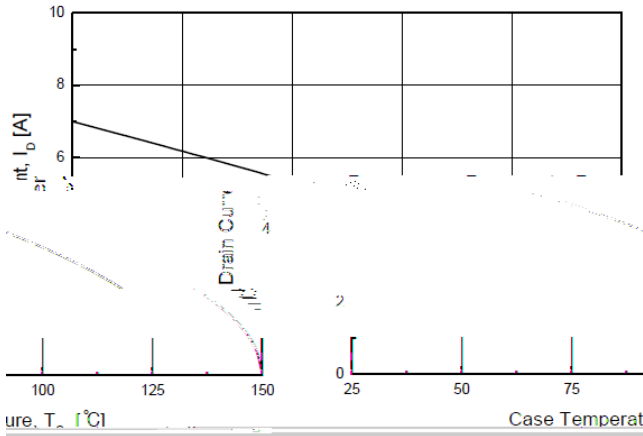
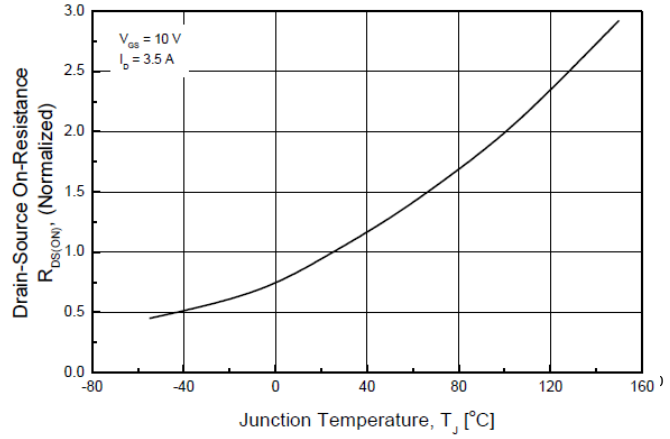
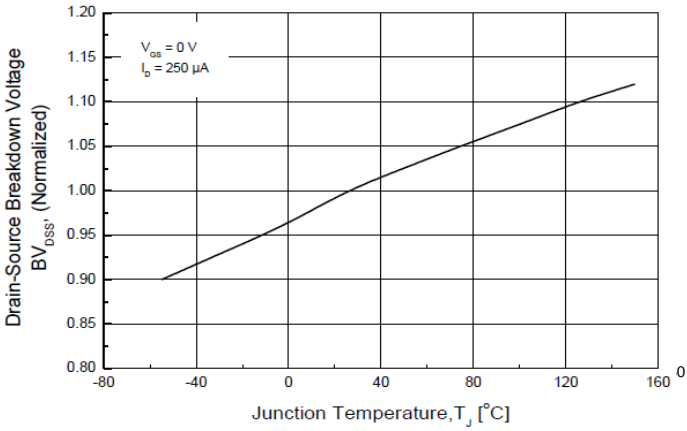
**SOURCE DRAIN DIODE**

Maximum Continuous Drain-Source Diode Forward Current	$I_S$	---	--	--	7	A
Maximum Pulsed Drain-Source Diode Forward Current	$I_{SM}$	---	--	--	28	A
Drain-Source Diode Forward Voltage	$V_{SD}$	$V_{GS} = 0\text{ V}, I_S = 7\text{ A}$	--	--	1.5	V
Reverse Recovery Time <sup>(Note 4)</sup>	$t_{rr}$	$V_{GS} = 0\text{ V}, I_S = 7\text{ A}$	--	464	--	ns
Reverse Recovery Charge <sup>(Note 4)</sup>	$Q_{rr}$	$di_F / dt = 100\text{ A}/\mu\text{s}$	--	4.7	--	$\mu\text{C}$

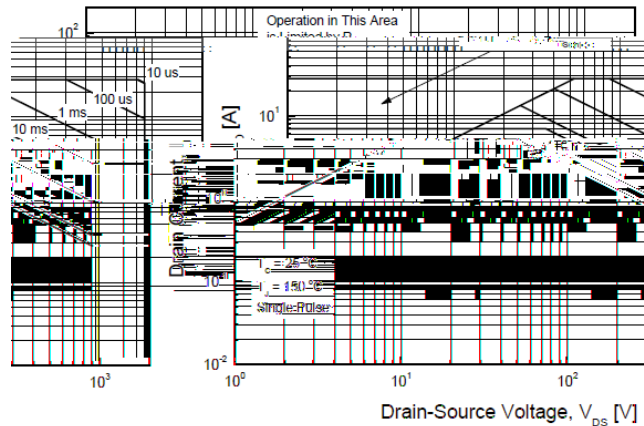
Note :

1. Repeated rating : Pulse width limited by safe operating area
2.  $L=4.1\text{mH}, I_{AS} = 7\text{A}, V_{DD} = 50\text{V}, R_G = 25$  , Starting  $T_J = 25$  , not subject to production test verified by design/characterization
3.  $I_{SD} = 7\text{A}, di/dt = \mu\text{s}, V_{DD} = 50\text{V}, V_{DS} = 720\text{V},$  Starting  $T_J = 25$
5. Essentially Independent of Operating Temperature Typical Characteristics

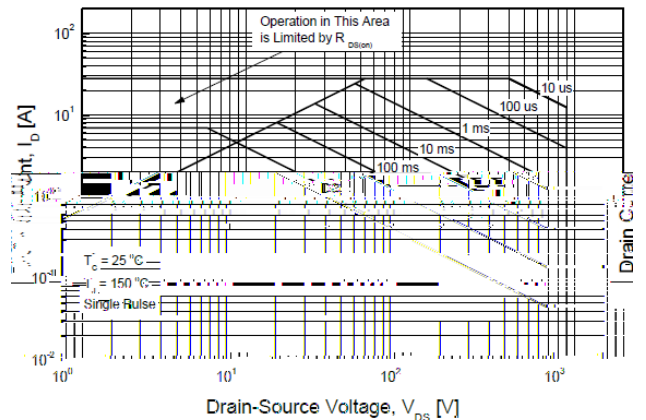




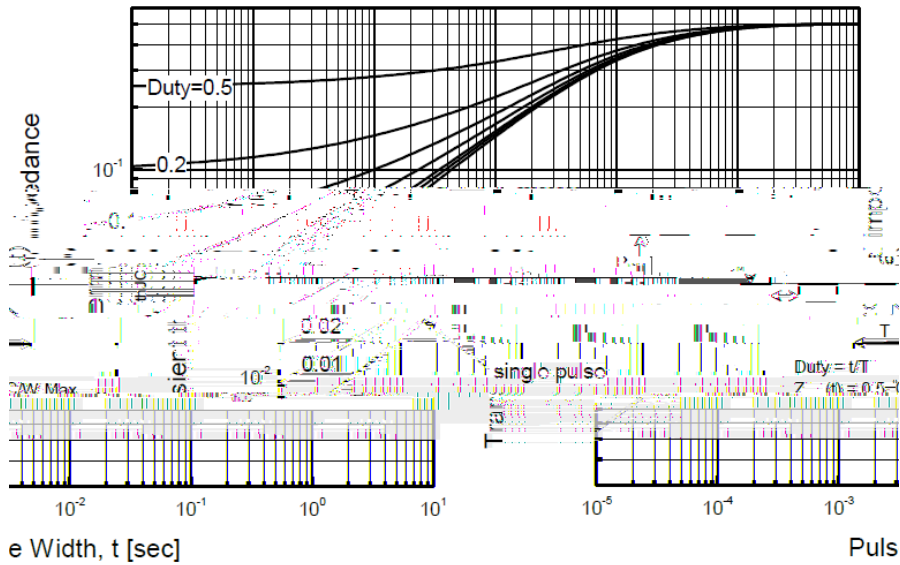
## TMP7N90



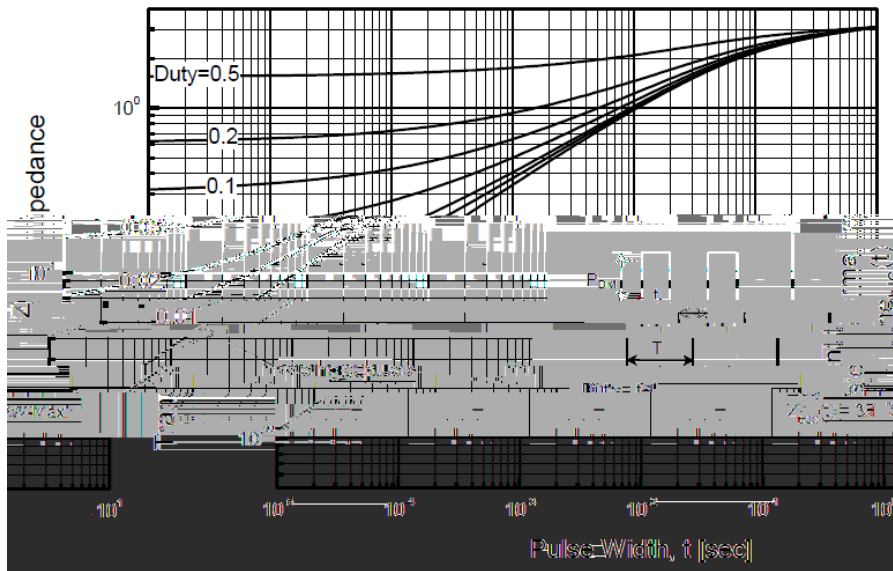
## TMPF7N90G



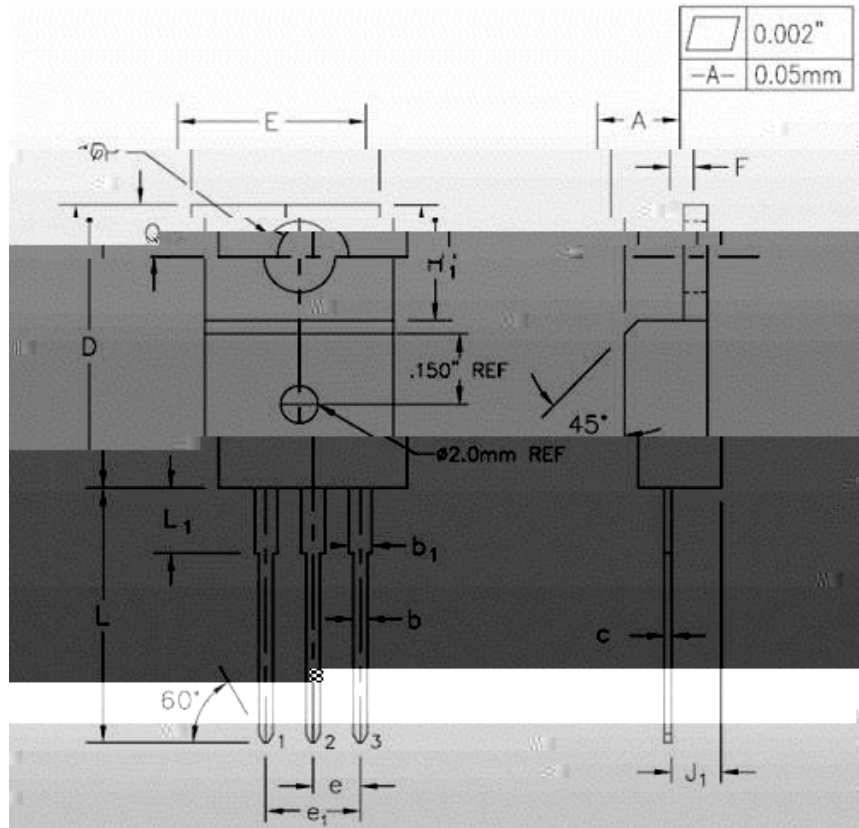
**TMP7N90**



**TMPF7N90G**

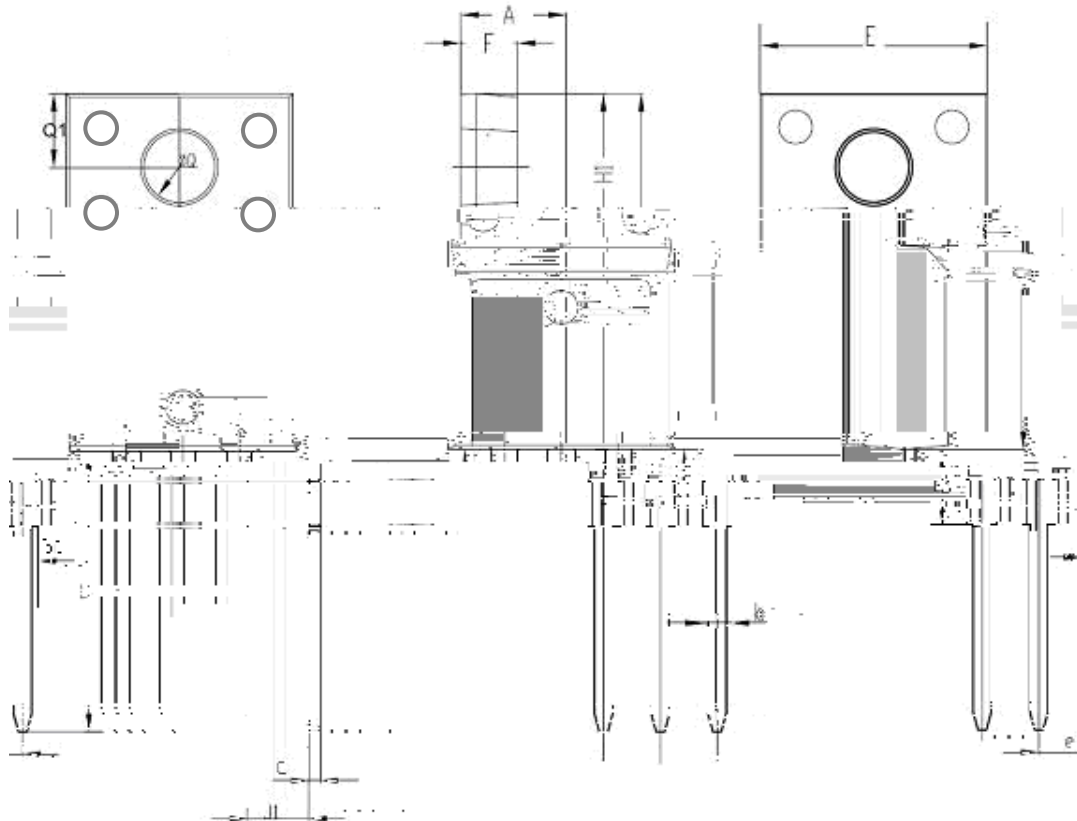


TO-220AB-3L MECHANICAL DATA



SYMBOL	INCHES		MILLIMETERS		NOTES
	MIN.	MAX.	MIN.	MAX.	
A	0.170	0.180	4.32	4.57	
b	0.028	0.036	0.71	0.91	
b <sub>1</sub>	0.045	0.055	1.15	1.39	
c	0.014	0.021	0.36	0.53	
D	0.590	0.610	14.99	15.49	
E	0.395	0.410	10.04	10.41	
e	0.100 TYP.		2.54 TYP.		
e <sub>1</sub>	0.200 BSC		5.08 BSC		
F	0.048	0.054	1.22	1.37	
H <sub>1</sub>	0.235	0.255	5.97	6.47	
J <sub>1</sub>	0.100	0.110	2.54	2.79	
L	0.530	0.550	13.41	13.97	
L <sub>1</sub>	0.130	0.150	3.31	3.81	
∅P	0.149	0.153	3.79	3.88	
Q	0.102	0.112	2.60	2.84	

TO-220F-3L MECHANICAL DATA



Q	MJ	L AFCQ		JJ	CRCPQ	LMRCQ
		L		L		
		. 56	. 72	2 31	2 71	
		. .06	. .14	. 5	. 7	
A		. . 6	. .02	. 23	. 4.	
B		. 4 5	. 411	3 45	4. 5	
C		. 170	. 2. 6	7 74	. 14	
		. . R N		0 32R N		
F		. 034	. 050	4 3.	4 7.	
H		. .	. 5	0 34	0 74	
J		. 3.1	. 3 7	0 56	1 6	
O		. 5	. 11	0 76	1 16	
		. .23	. .33	3	17	
J		. 2	. 1.	0 7	1 1	
O		. 00	. 16	1 .	1 3.	
D		. .70	. . 6	0 12	0 52	

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